

KSA928A TRANSISTOR (PNP)

FEATURE

Power dissipation

$$P_{CM}: 1 \text{ W (Tamb=25}^\circ\text{C)}$$

Collector current

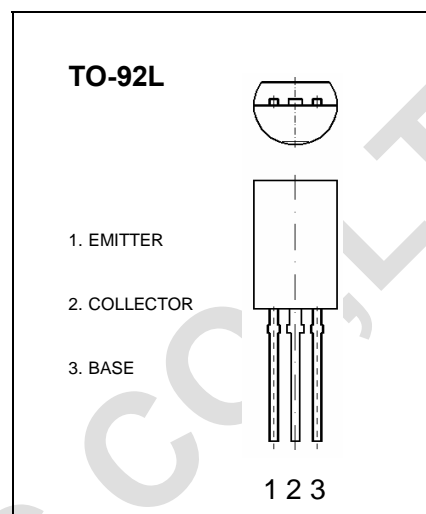
$$I_{CM}: -2 \text{ A}$$

Collector-base voltage

$$V_{(BR)CBO}: -30 \text{ V}$$

Operating and storage junction temperature range

$$T_J, T_{stg}: -55^\circ\text{C to } +150^\circ\text{C}$$



ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-30		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-30		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -1\text{mA}, I_C = 0$	-5		V
Collector cut-off current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0$		-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$		-0.1	μA
DC current gain	h_{FE}	$V_{CE} = -2 \text{ V}, I_C = -500\text{mA}$	100	320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1.5 \text{ A}, I_B = -0.03\text{A}$		-2	V
Base-emitter voltage	V_{BE}	$I_C = -500\text{mA}, V_{CE} = -2\text{V}$		-1	V
Transition frequency	f_T	$V_{CE} = -2 \text{ V}, I_C = -500\text{mA}$	100		MHz

CLASSIFICATION OF h_{FE}

Rank	O	Y
Range	100-200	160-320